

## LOW DROP POWER SCHOTTKY RECTIFIER

### MAIN PRODUCT CHARACTERISTICS

<b>I<sub>F(AV)</sub></b>	<b>2 x 10 A</b>
<b>V<sub>RRM</sub></b>	<b>25 V</b>
<b>T<sub>j</sub> (max)</b>	<b>150 °C</b>
<b>V<sub>F</sub> (max)</b>	<b>0.35 V</b>

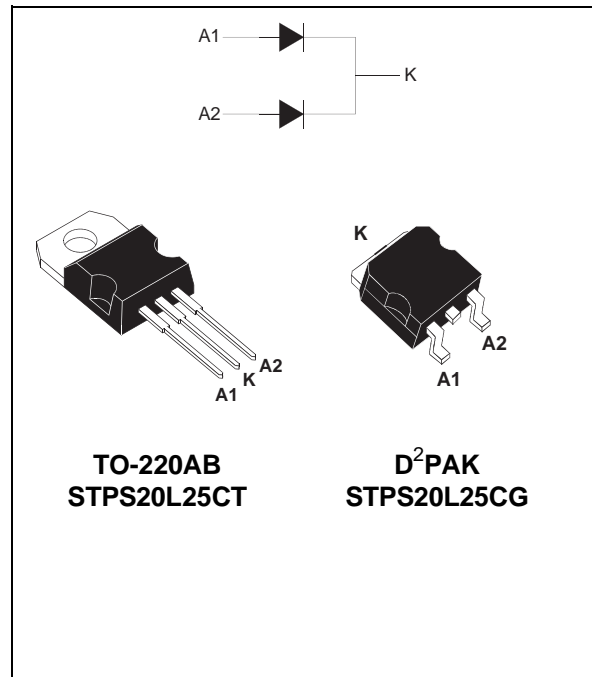
### FEATURES AND BENEFITS

- VERY LOW FORWARD VOLTAGE DROP FOR LESS POWER DISSIPATION AND REDUCED HEATSINK
- OPTIMIZED CONDUCTION/REVERSE LOSSES TRADE-OFF WHICH MEANS THE HIGHEST EFFICIENCY IN THE APPLICATIONS

### DESCRIPTION

Dual center tap Schottky rectifier suited to Switched Mode Power Supplies and high frequency DC to DC converters.

Packaged in TO-220AB and D<sup>2</sup>PAK, this device is especially intended for use as a rectifier at the secondary of 3.3V SMPS units.



**TO-220AB**  
**STPS20L25CT**

**D<sup>2</sup>PAK**  
**STPS20L25CG**

### ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter		Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage		25	V
I <sub>F(RMS)</sub>	RMS forward current		30	A
I <sub>F(AV)</sub>	Average forward current	T <sub>c</sub> = 145°C δ = 0.5	Per diode: 10 Per device: 20	A
I <sub>FSM</sub>	Surge non repetitive forward current	tp = 10 ms Sinusoidal	220	A
I <sub>R(RM)</sub>	Repetitive peak reverse current	tp=2 μs square F=1kHz	1	A
I <sub>R(SM)</sub>	Non repetitive peak reverse current	tp = 100 μs square	3	A
T <sub>stg</sub>	Storage temperature range		- 65 to + 150	°C
T <sub>j</sub>	Maximum operating junction temperature *		150	°C
dV/dt	Critical rate of rise of reverse voltage		10000	V/μs

\* :  $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$  thermal runaway condition for a diode on its own heatsink

# STPS20L25CT/CG

## THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case	Per diode	1.5	$^{\circ}\text{C}/\text{W}$
		Total	0.8	
$R_{th(c)}$		Coupling	0.1	

When the diodes 1 and 2 are used simultaneously :  
 $\Delta T_j(\text{diode 1}) = P(\text{diode 1}) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$

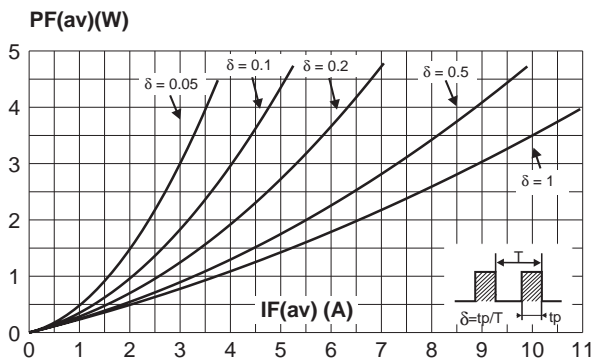
## STATIC ELECTRICAL CHARACTERISTICS (per diode)

Symbol	Tests conditions	Tests conditions	Min.	Typ.	Max.	Unit
$I_R^*$	Reverse leakage current	$T_j = 25^{\circ}\text{C}$	$V_R = V_{RRM}$		800	$\mu\text{A}$
		$T_j = 125^{\circ}\text{C}$		125	250	mA
$V_F^*$	Forward voltage drop	$T_j = 25^{\circ}\text{C}$	$I_F = 10\text{ A}$		0.46	V
		$T_j = 125^{\circ}\text{C}$	$I_F = 10\text{ A}$	0.30	0.35	
		$T_j = 25^{\circ}\text{C}$	$I_F = 20\text{ A}$		0.56	
		$T_j = 125^{\circ}\text{C}$	$I_F = 20\text{ A}$	0.41	0.48	

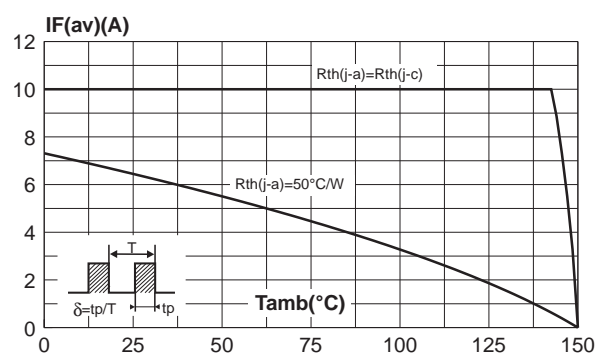
Pulse test : \*  $t_p = 380\ \mu\text{s}$ ,  $\delta < 2\%$

To evaluate the maximum conduction losses use the following equation :  
 $P = 0.22 \times I_{F(AV)} + 0.013 I_{F(RMS)}^2$

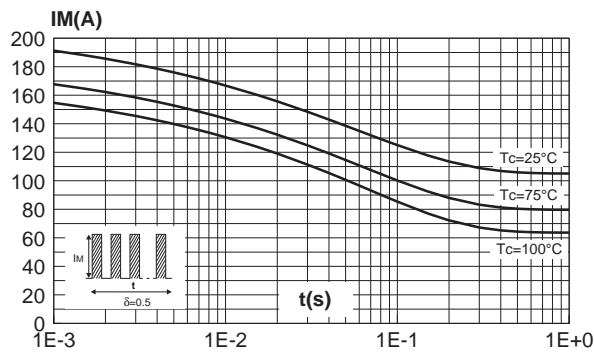
**Fig.1** : Average forward power dissipation versus average forward current.



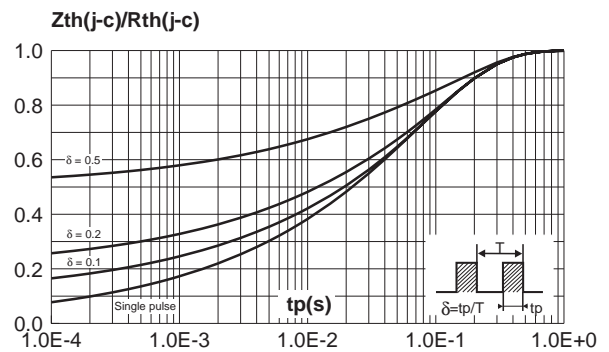
**Fig.2** : Average forward current versus ambient temperature ( $\delta = 0.5$ ).



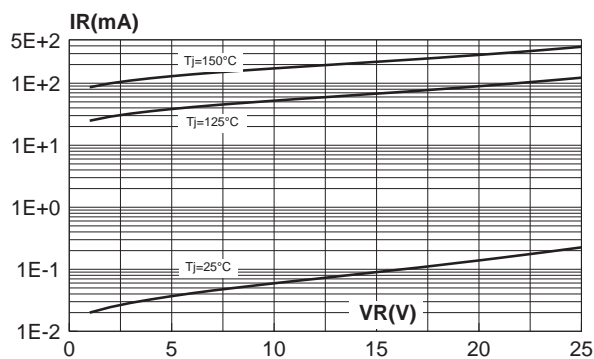
**Fig.3** : Non repetitive surge peak forward current versus overload duration (maximum values).



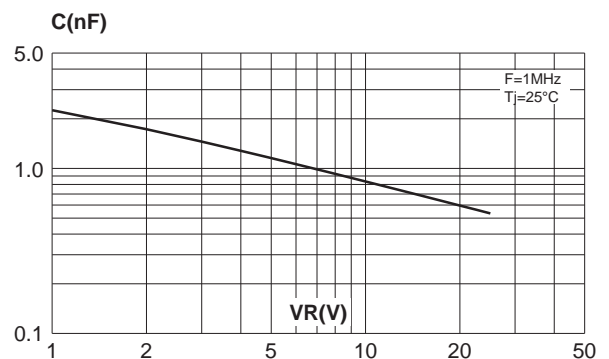
**Fig.4** : Relative variation of thermal impedance junction to case versus pulse duration.



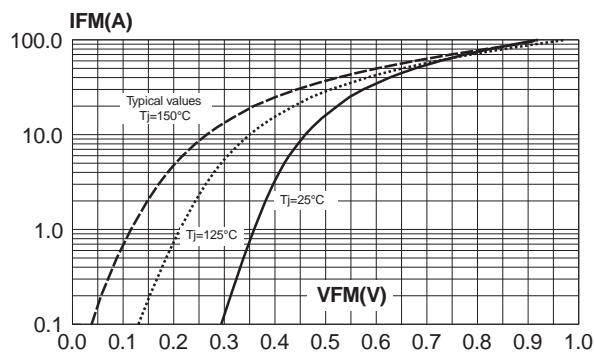
**Fig.5** : Reverse leakage current versus reverse voltage applied (typical values).



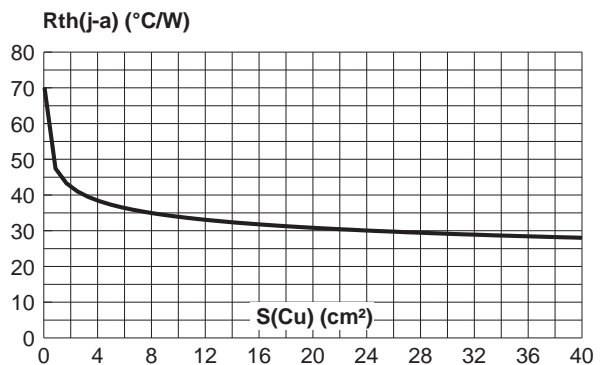
**Fig.6** : Junction capacitance versus reverse voltage applied (typical values).



**Fig.7** : Forward voltage drop versus forward current (maximum values).

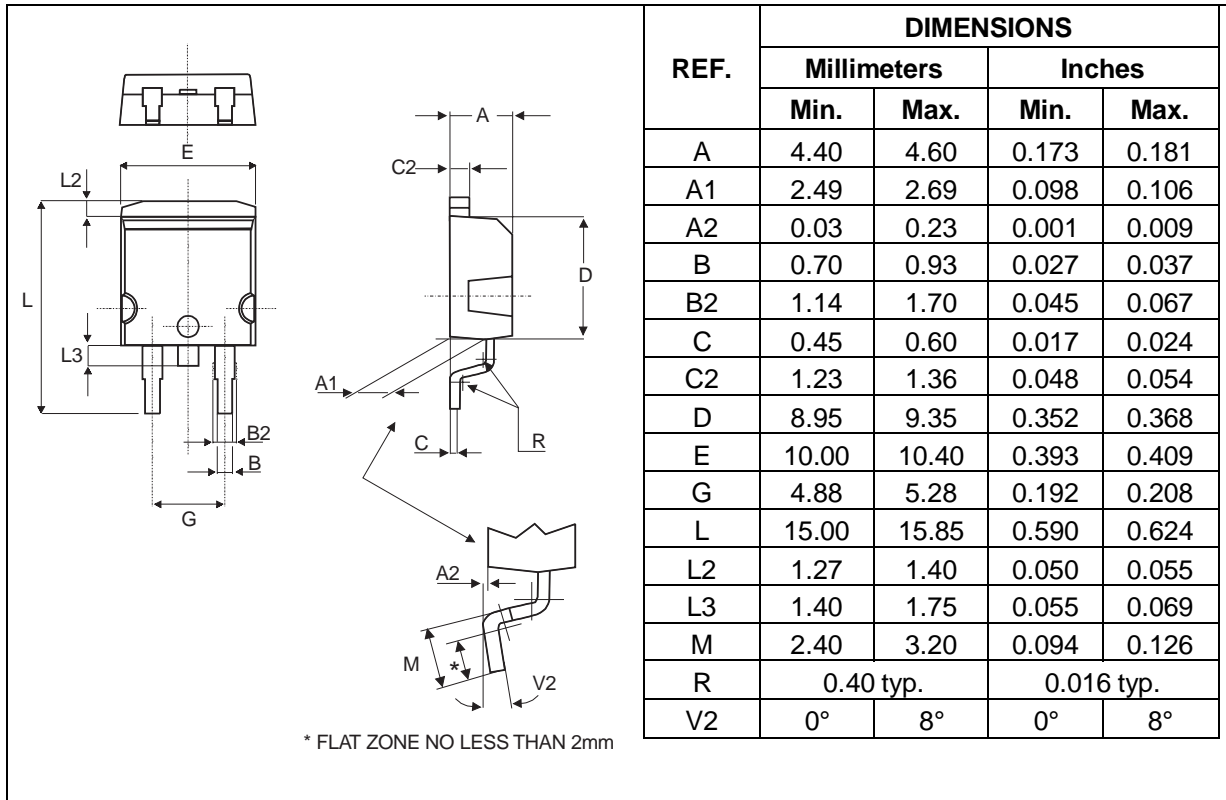


**Fig.8** : Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board FR4, copper thickness : 35 μm). (STPS20L25G only)

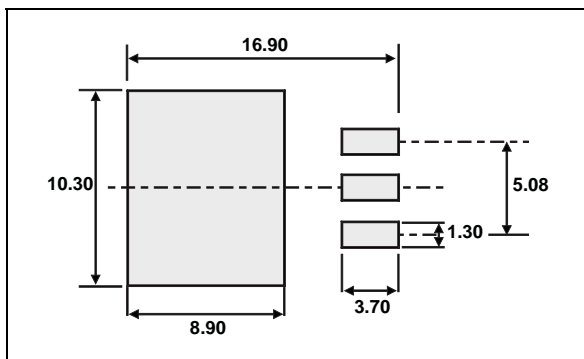


# STPS20L25CT/CG

## PACKAGE MECHANICAL DATA D<sup>2</sup>PAK

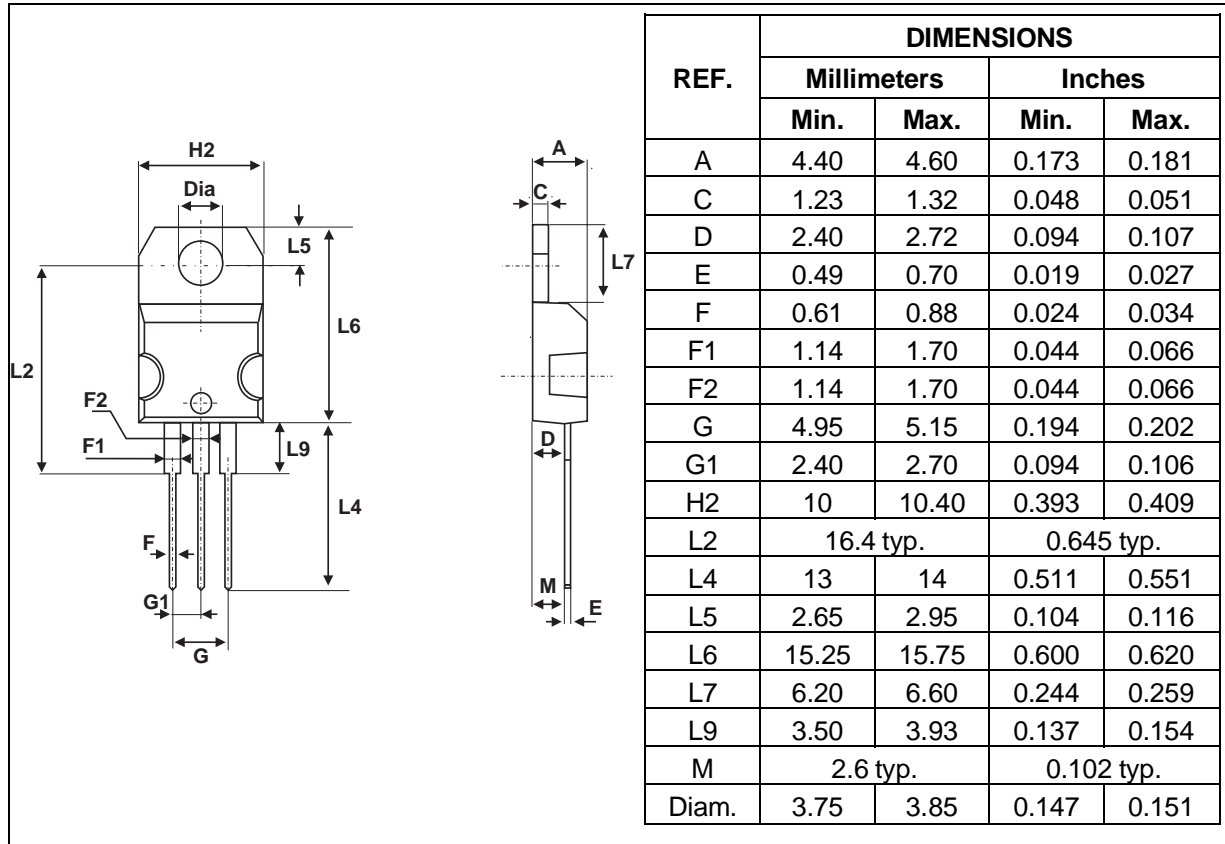


### FOOTPRINT DIMENSIONS (in millimeters)



- Cooling method: by conduction (method C)

**PACKAGE MECHANICAL DATA**  
TO-220AB



- Cooling method : C
- Recommended torque value : 0.55 m.N
- Maximum torque value : 0.70 m.N

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS20L25CT	STPS20L25CT	TO-220AB	2.23g	50	Tube
STPS20L25CG	STPS20L25CG	D <sup>2</sup> PAK	1.48g	50	Tube
STPS20L25CG-TR	STPS20L25CG	D <sup>2</sup> PAK	1.48g	1000	Tape & reel

- Epoxy meets UL94,V0

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